DESCRIPTION

The SPN8439 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

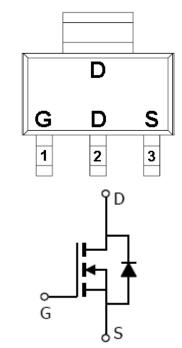
FEATURES

- 30V/6.2A,RDS(ON)= $42m\Omega(@VGS=4.5V$
- 30V/5.4A, RDS(ON)= $54m\Omega(@VGS=2.5V$
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOT-223 package design

APPLICATIONS

- Power Management in Note book
- DC/DC Converter
- LCD Display inverter

PIN CONFIGURATION(SOT-223)



PART MARKING



Y: Year Code W: Week Code

PIN DESCRIPTION				
Pin	Symbol	Description		
1	G	Gate		
2	D	Drain		
3	S	Source		

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN8439S22RG	SOT-223	8439

★ SPN8439S22RG : Tape Reel ; Pb – Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

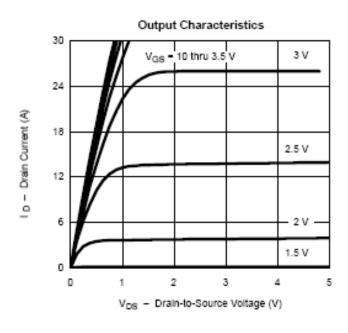
Parameter		Symbol	Typical	Unit
Drain-Source Voltage		Vdss	30	V
Gate –Source Voltage		VGSS	±12	V
Continuous Dusin Comment/Tr-1509C)	Ta=25°C	- Id	5.8	Δ.
Continuous Drain Current(T _J =150°C)	Ta=70°C		4.2	A
Pulsed Drain Current		Ірм	25	A
Continuous Source Current(Diode Conduction)		Is	1.7	A
Parama Dissination	Ta=25°C	PD	2.8	XX.
Power Dissipation	Ta=70°C		1.2	W
Operating Junction Temperature		TJ	150	°C
Storage Temperature Range		Tstg	-55/150	°C
Thermal Resistance-Junction to Ambient		R _θ JA	90	°C/W

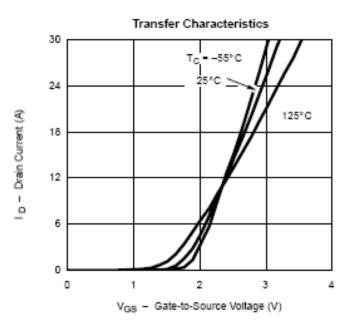
ELECTRICAL CHARACTERISTICS

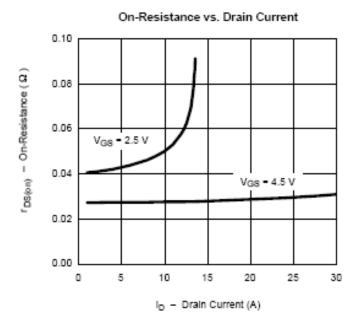
(TA=25°C Unless otherwise noted)

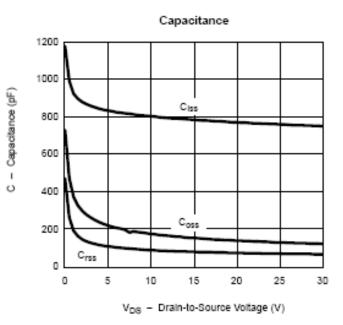
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static	<u>.</u>		•				
Drain-Source Breakdown Voltage	V(BR)DSS	Vgs=0V,Id=250uA	30			V	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.8		1.6	\ \ \ \ \	
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±100	nA	
		VDS=24V,VGS=1.0V			1		
Zero Gate Voltage Drain Current	IDSS	VDS=24V,VGS=0.0V TJ=55°C			10	uA	
On-State Drain Current	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 4.5V$	10			A	
Drain-Source On-Resistance	RDS(on)	VGS =4.5V,ID=6.2A VGS =2.5V,ID=5.4A		0.034 0.040	0.042 0.054	Ω	
Forward Transconductance	gfs	VDS=4.5V,ID=5.4A		12		S	
Diode Forward Voltage	Vsd	Is=1.7A,VGS=0V		0.8	1.2	V	
Dynamic							
Total Gate Charge	Qg			10	18		
Gate-Source Charge	Qgs	VDS=15VGS=10V ID=6.7A		1.6		nC	
Gate-Drain Charge	Qgd	-ID-0.7A		3.2			
Input Capacitance	Ciss			450			
Output Capacitance	Coss	V _{DS} =15V _{GS} =0V f=1MHz		240		pF	
Reverse Transfer Capacitance	Crss			38			
Turn-On Time	td(on)			7	15		
	tr	VDD=15RL=15		10	20	1	
T. 000T'	td(off)	ID=1.0A,VGEN=10 RG=6Ω		20	40	ns	
Turn-Off Time	tf			11	20		

TYPICAL CHARACTERISTICS

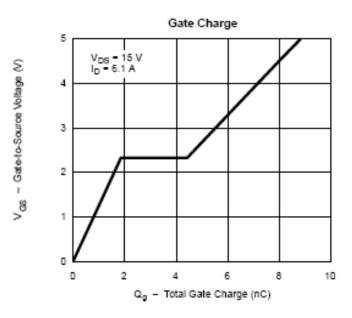


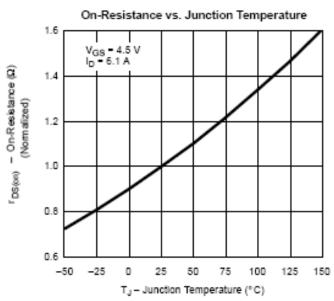


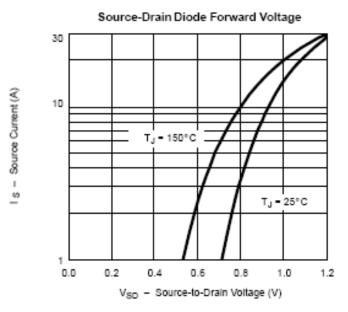


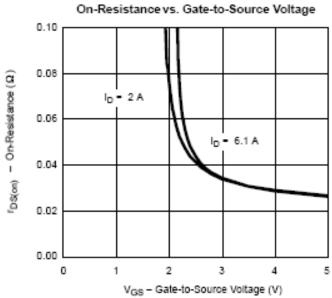


TYPICAL CHARACTERISTICS

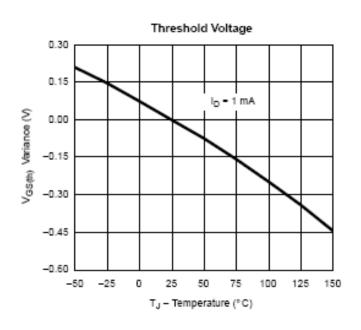


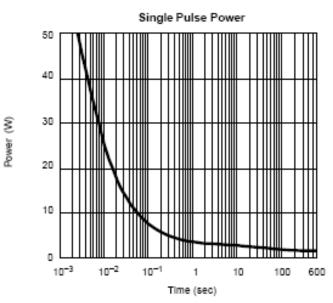


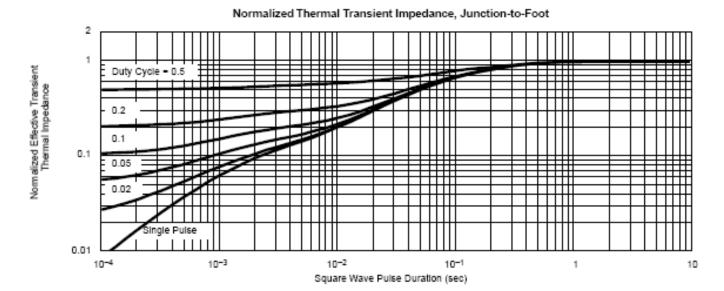




TYPICAL CHARACTERISTICS

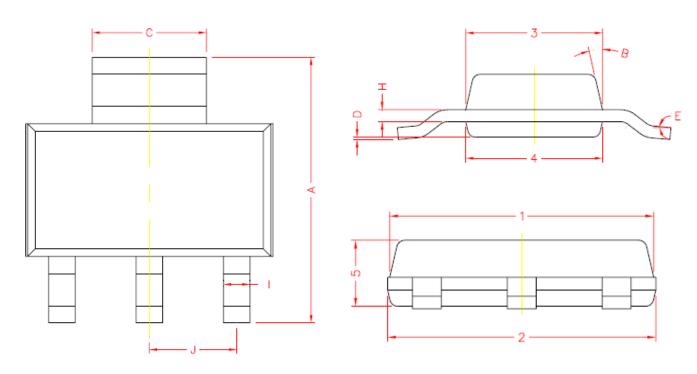








SOT-233 PACKAGE OUTLINE



	DIMENSIONS		
REF.	Millimeters		
	Min.	Max.	
Α	6.70	7.30	
С	2.90	3.10	
D	0.02	0.10	
Ε	0*	10°	
- 1	0.60	0.80	
Н	0.25	0.35	
В	13° TYP.		
J	2.30 REF.		
1	6.30	6.70	
2	6.30	6.70	
3	3.30	3.70	
4	3.30	3.70	
5	1.40	1.80	

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